

Unit VIII - Circuits

Voltage - potential difference (V)

- cause of current (flow of charge)

Current (I) - the rate of flow of charge

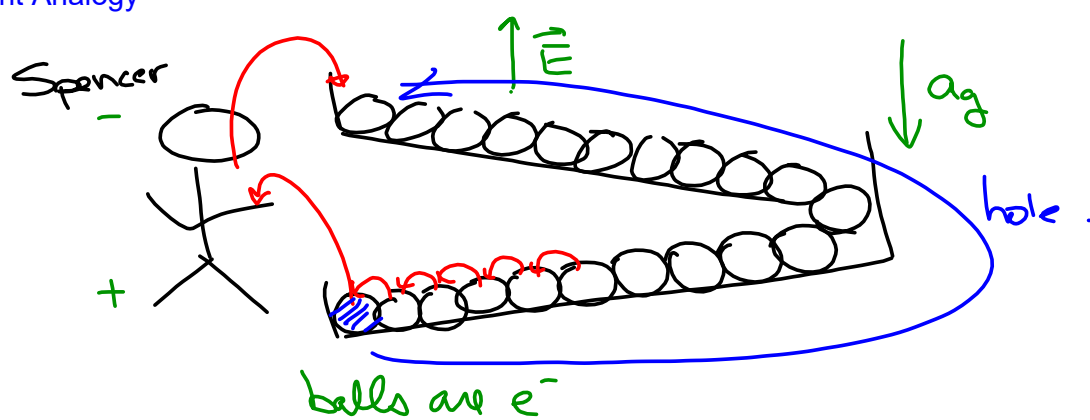
$$I = \frac{dQ}{dt} = \frac{Q}{t} \quad \leftarrow (I_{ave})$$

(charge passing by a point per unit time)

equal for direct current.

Current is defined as moving from + to -

A Current Analogy



Resistance (R) The opposition to the flow of current

$$R = \frac{V}{I} \quad \text{units } \frac{V}{C/s} = \frac{J_s}{C^2} = \Omega$$

ohm

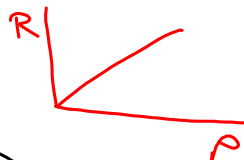
$$\frac{1}{\Omega} = \Omega^{-1} = \text{mho} \therefore$$

Factors that affect resistance

1. Substance - resistivity, $\rho (\Omega \cdot m)$ $\uparrow \rho \Rightarrow$ insulator

$R \propto \rho$
 \uparrow proportional to

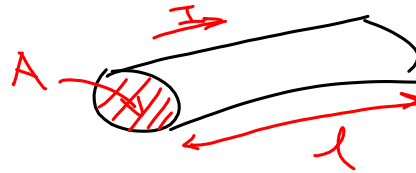
$\downarrow \rho \Rightarrow$ conductor



2. Length (l) - $R \propto l$

3. Cross-sectional area (A)

$$R \propto \frac{1}{A}$$



4. Temperature (T) - for Most substances

$\uparrow T \Rightarrow \uparrow R$

(semiconductors are the exception)
 - for s.c.

resistivity is a function of T

$$\rho(T) = \rho_0 (1 + \alpha \Delta T)$$

value of ρ at some T.

temp coefficient p.535

If ΔT is small this equation holds.

This is a 1st order approximation

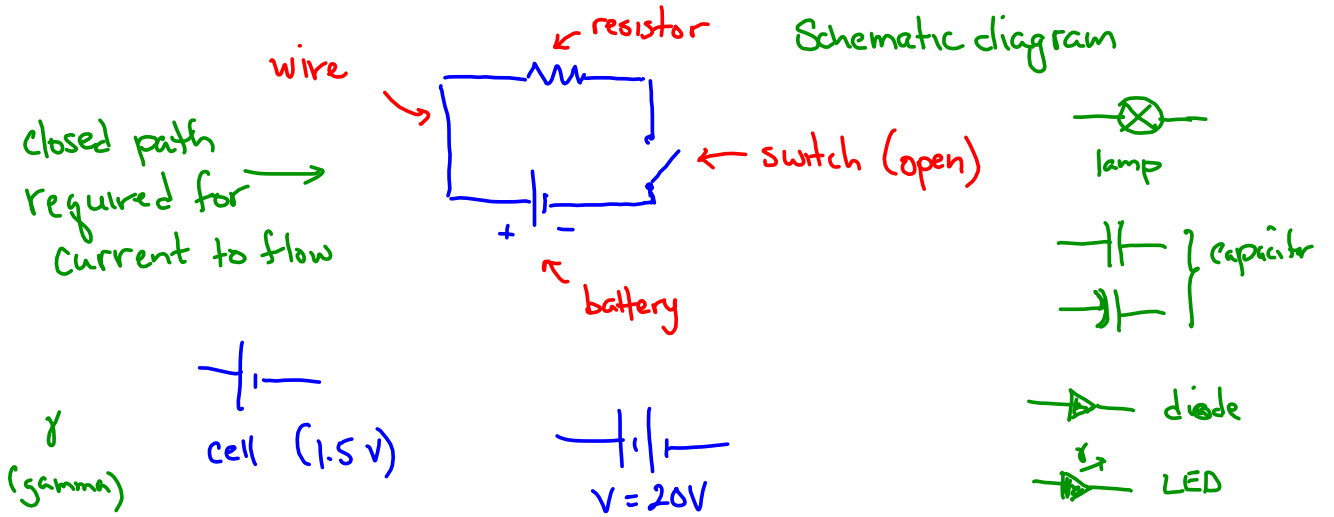
$$(\rho = \rho_0 (1 + \alpha \Delta T + \beta (\Delta T)^2 + \gamma (\Delta T)^3 + \dots))$$

$$R = \frac{\rho(T)l}{A}$$

A Simple Circuit - 3 components + 1 optional

- Required
- 1. Source - provides potential difference (energy)
 - 2. Sink - uses the energy
 - 3. Path - allows the motion of current from source to sink and back

Optional 4. Control Switch - opens/closes the path



Ohm's Law

Georg Simon Ohm found that for metal conductors at constant temperature

$$R = \frac{V}{I} = \text{constant},$$

